

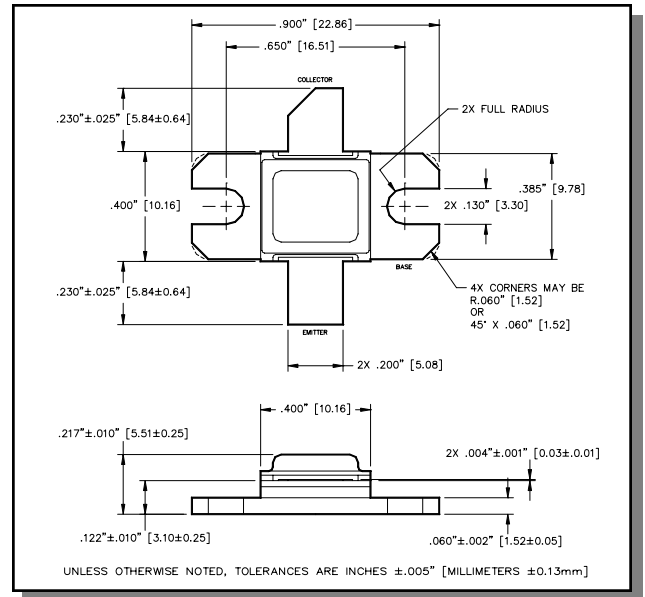
Radar Pulsed Power Transistor 100W, 1.2-1.4 GHz, 2ms Pulse, 20% Duty

M/A-COM Products
Released, 30 May 07

Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

Outline Drawing



Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V_{CES}	75	V
Emitter-Base Voltage	V_{EBO}	3.0	V
Collector Current (Peak)	I_C	14.1	A
Power Dissipation @ +25°C	P_{TOT}	250	W
Storage Temperature	T_{STG}	-65 to +200	°C
Junction Temperature	T_J	200	°C

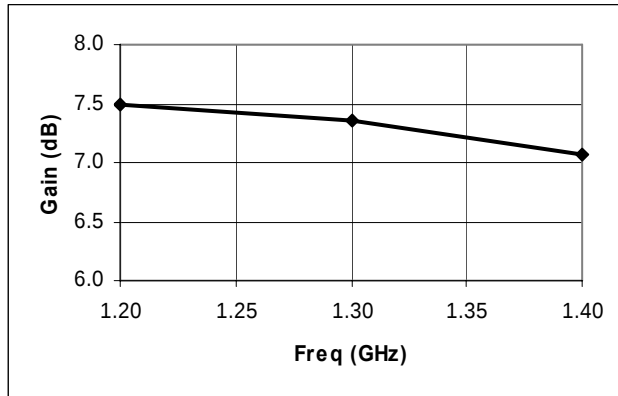
Electrical Specifications: $T_C = 25 \pm 5^\circ\text{C}$ (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	$I_C = 50\text{mA}$		BV_{CES}	70	-	V
Collector-Emitter Leakage Current	$V_{CE} = 28\text{V}$		I_{CES}	-	10	mA
Thermal Resistance	$V_{CC} = 28\text{V}$, $P_{in} = 25\text{W}$	$F = 1.2, 1.3, 1.4\text{ GHz}$	$R_{TH(JC)}$	-	0.7	°C/W
Output Power	$V_{CC} = 28\text{V}$, $P_{in} = 25\text{W}$	$F = 1.2, 1.3, 1.4\text{ GHz}$	P_{OUT}	100	-	W
Power Gain	$V_{CC} = 28\text{V}$, $P_{in} = 25\text{W}$	$F = 1.2, 1.3, 1.4\text{ GHz}$	G_P	6.0	-	dB
Collector Efficiency	$V_{CC} = 28\text{V}$, $P_{in} = 25\text{W}$	$F = 1.2, 1.3, 1.4\text{ GHz}$	η_C	52	-	%
Input Return Loss	$V_{CC} = 28\text{V}$, $P_{in} = 25\text{W}$	$F = 1.2, 1.3, 1.4\text{ GHz}$	RL	-	-8	dB
Load Mismatch Tolerance	$V_{CC} = 28\text{V}$, $P_{in} = 25\text{W}$	$F = 1.2, 1.3, 1.4\text{ GHz}$	VSWR-T	-	3:1	-
Load Mismatch Stability	$V_{CC} = 28\text{V}$, $P_{in} = 25\text{W}$	$F = 1.2, 1.3, 1.4\text{ GHz}$	VSWR-S	-	1.5:1	-

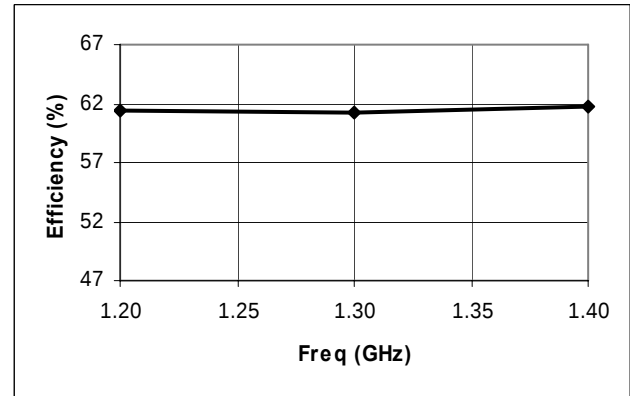
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Gain vs. Frequency

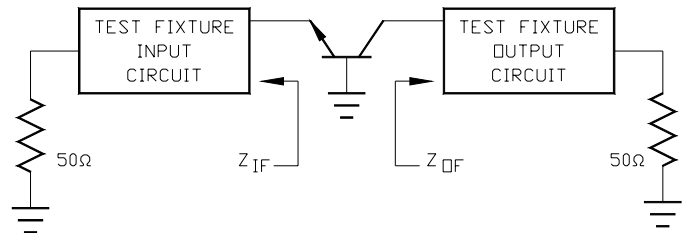


Collector Efficiency vs. Frequency



RF Test Fixture Impedance

F (GHz)	Z_{IF} (Ω)	Z_{OF} (Ω)
1.2	$2.6 - j3.8$	$3.0 - j2.7$
1.3	$3.0 - j3.4$	$2.4 - j2.6$
1.4	$3.4 - j3.1$	$1.9 - j2.5$



Test Fixture Circuit Dimensions

